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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Letavic et al.) Examiner: Lewis, M.
Application No.: 10/015,847)
Filed: 12/10/2001) Art Unit: 2822
For: DUAL GATE OXIDE HIGH-VOLTAGE) Confirmation No.: 3619
SEMICONDUCTOR DEVICE)

Commissioner for Patents
P.O. Box 1450
Alexandria VA 22313-1450

AFTER FINAL AMENDMENT

Sir:

Applicants thank the Examiner for conducting a telephone interview on August 13, 2003 regarding this response. The content of this telephone interview is incorporated in the Remarks portion of this amendment. In response to the Final Office Action of May 14, 2003, please amend the above-identified application as follows:

Amendments to the Drawings begin on page 2 of this paper and include both attached replacement sheets and annotated sheets showing the changes made.

Remarks begin on page 3 of this paper.

An Appendix including replacement sheets and marked up sheets is attached following page 4 of this paper.

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AUG 20 2003
TECHNOLOGY CENTER 2800